

TO-252 Pin Configuration

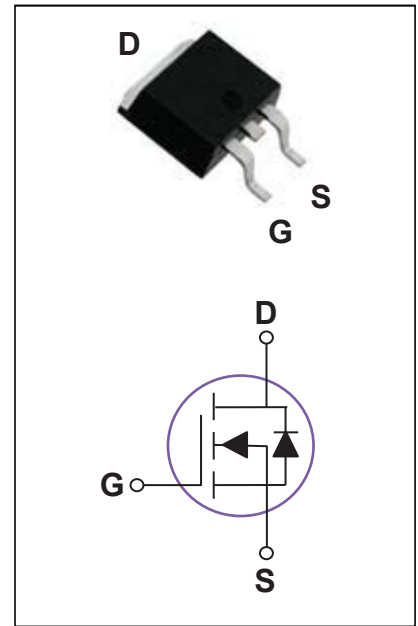
| | | |
|-------|---------------------|----------------|
| BVDSS | R _{DS(ON)} | I _D |
| 30V | 4.1mΩ | 74A |

Features

- 30V, 74A, $R_{DS(ON)} = 4.1m\Omega @ V_{GS} = 10V$
- Improved dv/dt capability
- Fast switching
- 100% EAS Guaranteed
- Green Device Available

Applications

- Networking
- Load Switch
- LED applications



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

| Parameter | Symbol | Rating | Units |
|---|------------------|-------------|-------|
| Drain-Source Voltage | V _{DS} | 30 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current – Continuous (TC=25°C) | I _D | 74 | A |
| Drain Current – Continuous (TC=100°C) | | 46.8 | A |
| Drain Current – Pulsed ¹ | I _{DM} | 296 | A |
| Single Pulse Avalanche Energy ² | E _{AS} | 115 | mJ |
| Single Pulse Avalanche Current ² | I _{AS} | 48 | A |
| Power Dissipation (TC=25°C) | P _D | 54.3 | W |
| Power Dissipation – Derate above 25°C | | 0.44 | W/°C |
| Storage Temperature Range | T _{STG} | -50 to +150 | °C |
| Operating Junction Temperature Range | T _J | -50 to +150 | °C |

Thermal Characteristics

| Parameter | Symbol | Typ. | Max. | Unit |
|--|------------------|------|------|------|
| Thermal Resistance Junction to ambient | R _{θJA} | --- | 62 | °C/W |
| Thermal Resistance Junction to Case | R _{θJC} | --- | 2.3 | °C/W |

MOSFET ELECTRICAL CHARACTERISTICS $T_A=25^{\circ}\text{C}$ unless otherwise specified

Off Characteristics

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|------------------------------------|------------------------------|--|-----|------|-----------|----------------------|
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 30 | --- | --- | V |
| BV_{DSS} Temperature Coefficient | $\Delta BV_{DSS}/\Delta T_J$ | Reference to 25°C , $I_D=1\text{mA}$ | --- | 0.03 | --- | $V/^{\circ}\text{C}$ |
| Drain-Source Leakage Current | I_{DSS} | $V_{DS}=30V, V_{GS}=0V, T_J=25^{\circ}\text{C}$ | --- | --- | 1 | μA |
| | | $V_{DS}=24V, V_{GS}=0V, T_J=125^{\circ}\text{C}$ | --- | --- | 10 | μA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | --- | --- | ± 100 | nA |

On Characteristics

| | | | | | | |
|--------------------------------------|---------------------|-------------------------------|-----|-------|-----|------------------------------|
| Static Drain-Source On-Resistance | $R_{DS(ON)}$ | $V_{GS}=10V, I_D=15A$ | --- | 3.4 | 4.1 | m Ω |
| | | $V_{GS}=4.5V, I_D=10A$ | --- | 4.7 | 6 | m Ω |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{GS}=V_{DS}, I_D=250\mu A$ | 1.0 | 1.6 | 2.5 | V |
| $V_{GS(th)}$ Temperature Coefficient | $\Delta V_{GS(th)}$ | | --- | -4.17 | --- | $\text{mV}/^{\circ}\text{C}$ |
| Forward Transconductance | g_{fs} | $V_{DS}=10V, I_D=3A$ | --- | 10 | --- | S |

Dynamic and switching Characteristics

| | | | | | | |
|-------------------------------------|--------------|---|-----|------|------|----------|
| Total Gate Charge ^{3, 4} | Q_g | $V_{DS}=15V, V_{GS}=10V, I_D=15A$ | --- | 34.6 | 70 | nC |
| Gate-Source Charge ^{3, 4} | Q_{gs} | | --- | 5.5 | 11 | |
| Gate-Drain Charge ^{3, 4} | Q_{gd} | | --- | 6.8 | 13 | |
| Turn-On Delay Time ^{3, 4} | $T_{d(on)}$ | $V_{DD}=15V, V_{GS}=10V, R_G=3.3\Omega$ $I_D=1A$ | --- | 9.7 | 20 | ns |
| Rise Time ^{3, 4} | T_r | | --- | 15.8 | 31 | |
| Turn-Off Delay Time ^{3, 4} | $T_{d(off)}$ | | --- | 37.4 | 75 | |
| Fall Time ^{3, 4} | T_f | | --- | 12 | 24 | |
| Input Capacitance | C_{iss} | $V_{DS}=15V, V_{GS}=0V, F=1\text{MHz}$ | --- | 1910 | 3800 | pF |
| Output Capacitance | C_{oss} | | --- | 300 | 600 | |
| Reverse Transfer Capacitance | C_{rss} | | --- | 230 | 460 | |
| Gate resistance | R_g | $V_{GS}=0V, V_{DS}=0V, F=1\text{MHz}$ | --- | 1.14 | --- | Ω |

Drain-Source Diode Characteristics and Maximum Ratings

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|---------------------------|----------|---|------|------|------|---------|
| Continuous Source Current | I_S | $V_G=V_D=0V$, Force Current | --- | --- | 74 | A |
| Pulsed Source Current | I_{SM} | | --- | --- | 148 | A |
| Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=1A, T_J=25^{\circ}\text{C}$ | --- | --- | 1 | V |
| Reverse Recovery Time | t_{rr} | $V_{DS}=30V, I_S=10A, di/dt=100A/\mu s$ | --- | 2.33 | --- | μs |
| Reverse Recovery Charge | Q_{rr} | $T_J=25^{\circ}\text{C}$ | --- | 48.9 | --- | μC |

Note :

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2. $V_{DD}=25V, V_{GS}=10V, L=0.1\text{mH}, I_{AS}=48A., R_G=25\Omega, \text{Starting } T_J=25^{\circ}\text{C}$.
3. The data tested by pulsed, pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
4. Essentially independent of operating temperature.

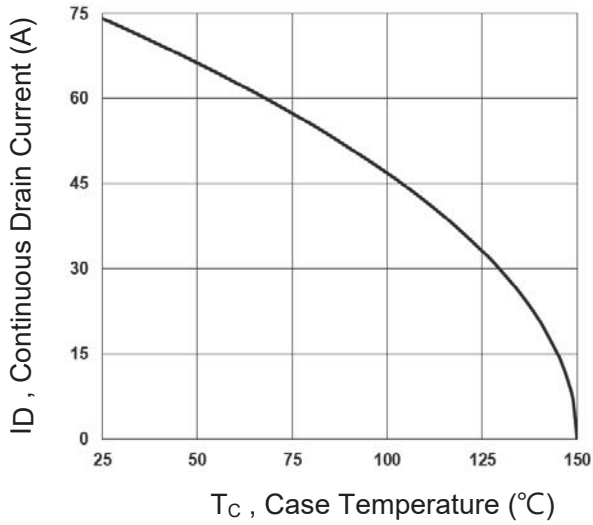


Fig.1 Continuous Drain Current vs. TC

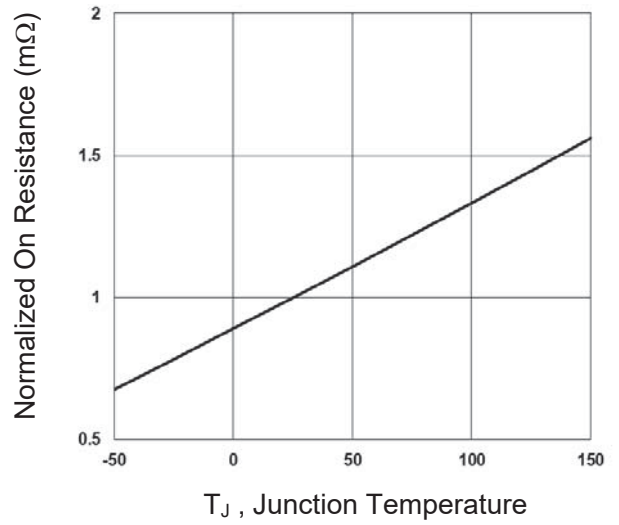


Fig.2 Normalized RDSON vs. TJ

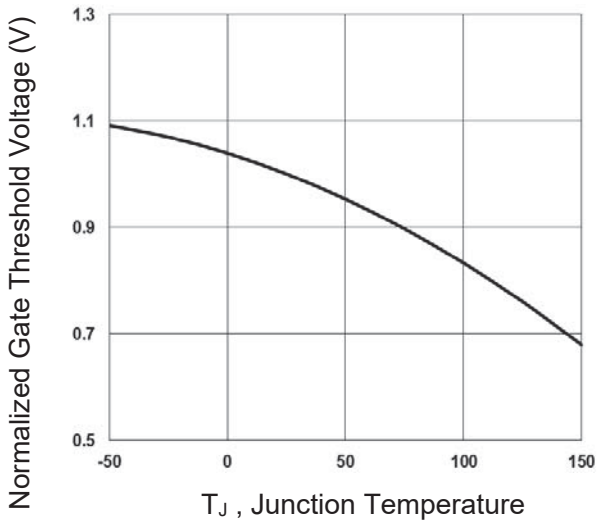


Fig.3 Normalized V_{th} vs. T_J

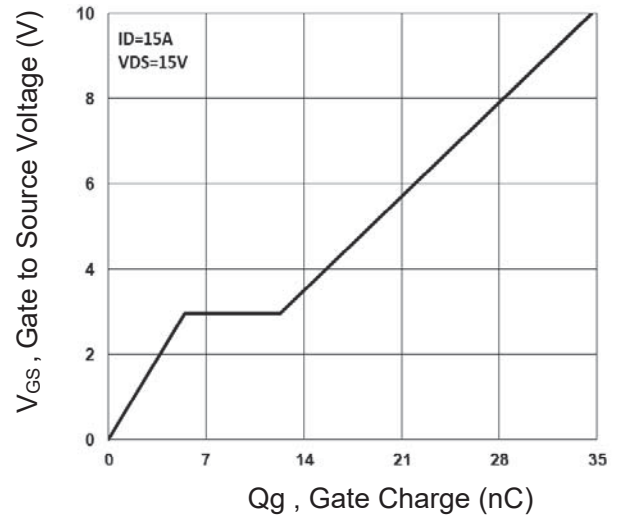


Fig.4 Gate Charge Characteristics

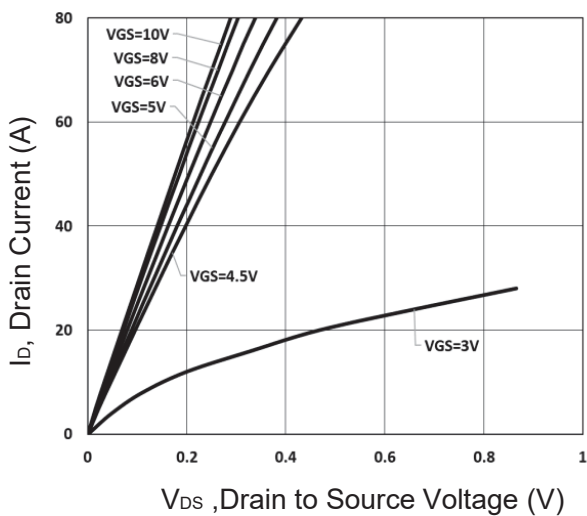


Fig.5 Typical Output Characteristics

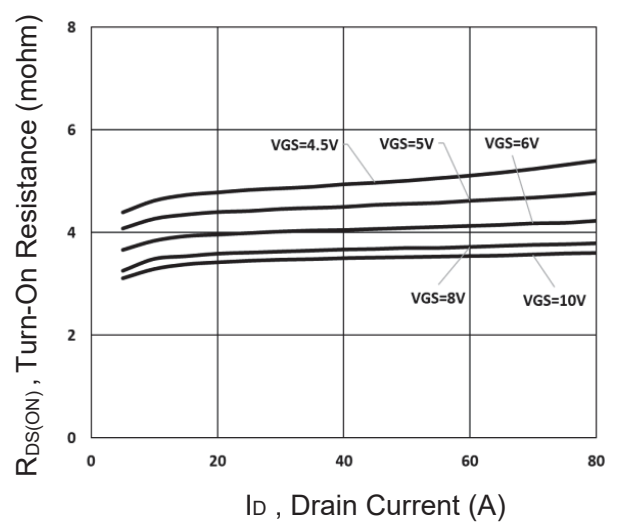
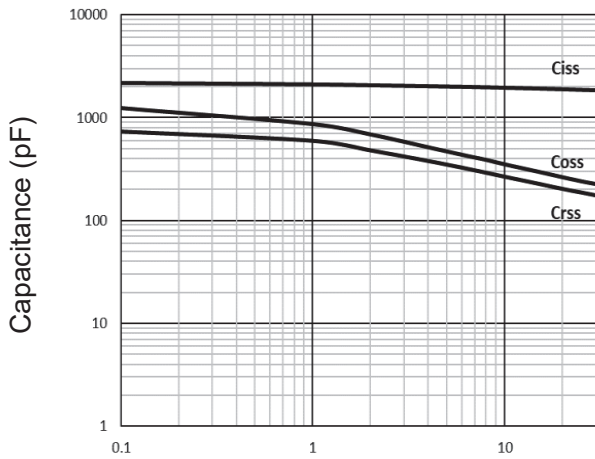


Fig.6 Turn-On Resistance vs. I_D



V_{DS} , Drain to Source Voltage (V)
Fig.7 Capacitance Characteristics

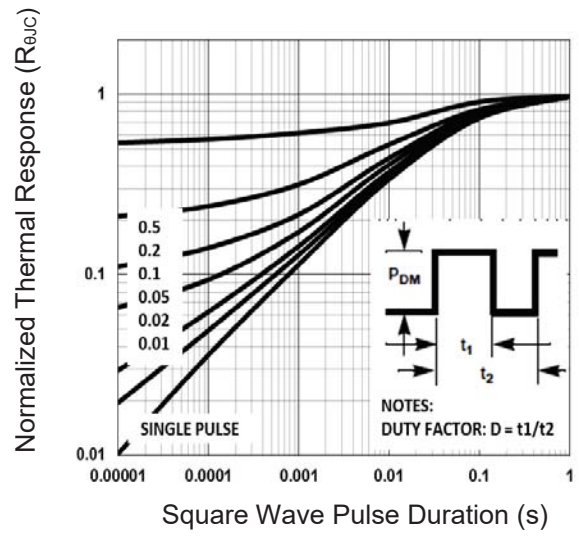


Fig.8 Normalized Transient Impedance

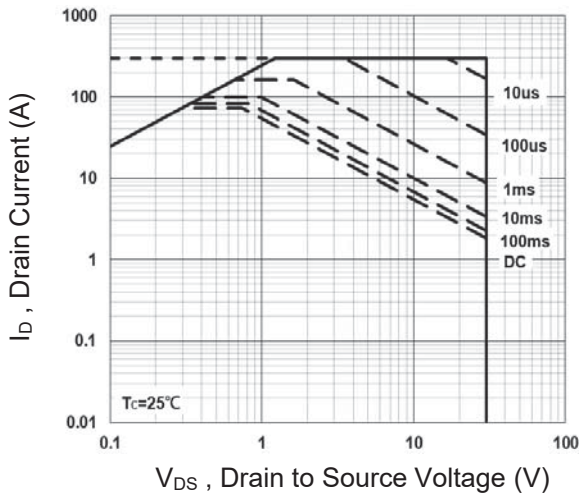


Fig.9 Maximum Safe Operation Area

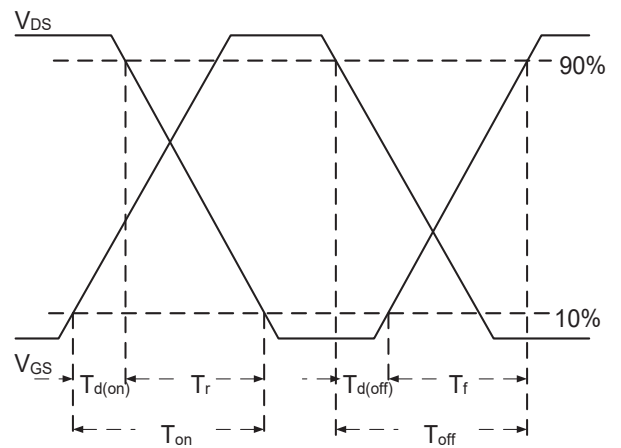


Fig.10 Switching Time Waveform

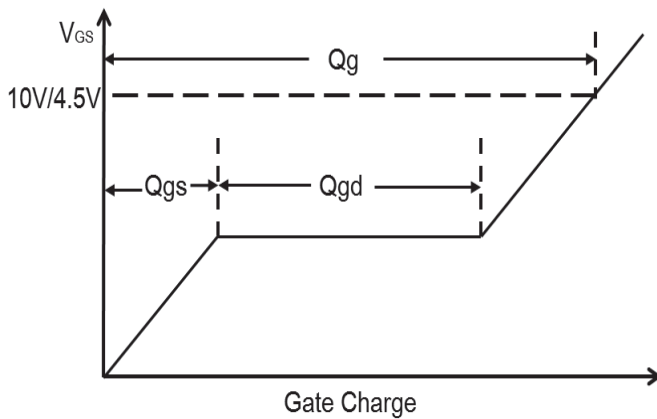
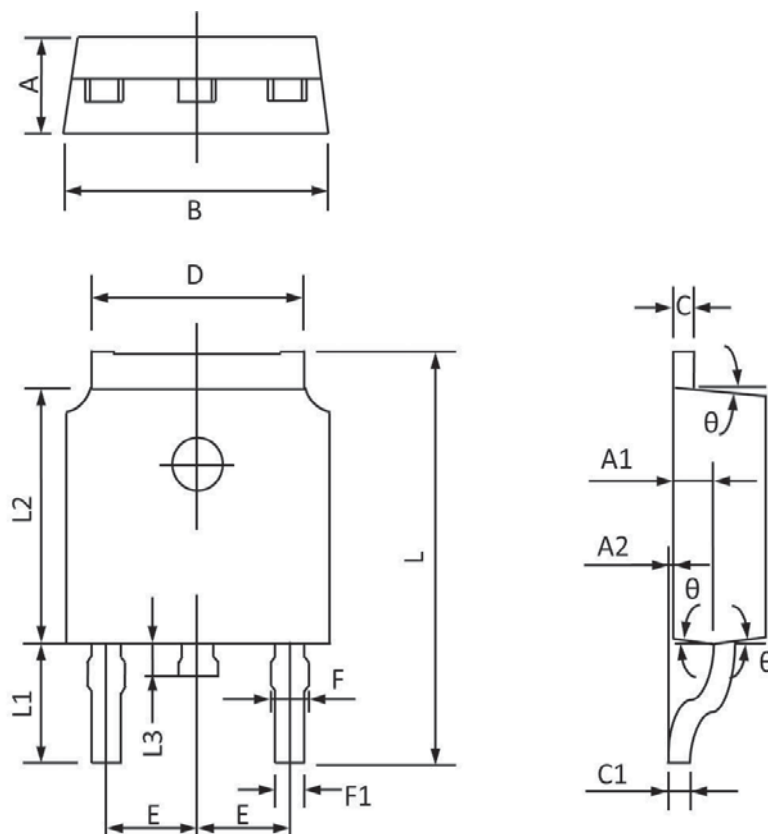


Fig.11 Gate Charge Waveform

TO-252 PACKAGE INFORMATION



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | MAX | MIN | MAX | MIN |
| A | 2.400 | 2.200 | 0.094 | 0.087 |
| A1 | 1.110 | 0.910 | 0.044 | 0.036 |
| A2 | 0.150 | 0.000 | 0.006 | 0.000 |
| B | 6.800 | 6.400 | 0.268 | 0.252 |
| C | 0.580 | 0.450 | 0.023 | 0.018 |
| C1 | 0.580 | 0.460 | 0.023 | 0.018 |
| D | 5.500 | 5.100 | 0.217 | 0.201 |
| E | 2.386 | 2.186 | 0.094 | 0.086 |
| F | 0.940 | 0.600 | 0.037 | 0.024 |
| F1 | 0.860 | 0.500 | 0.034 | 0.020 |
| L | 10.400 | 9.400 | 0.409 | 0.370 |
| L1 | 3.000 | 2.400 | 0.118 | 0.094 |
| L2 | 6.200 | 5.400 | 0.244 | 0.213 |
| L3 | 1.200 | 0.600 | 0.047 | 0.024 |
| θ | 9° | 3° | 9° | 3° |